≥ EnOcean

Scavenger Transceiver Module
STM 400J

11 September 2020

Observe precautions! Electrostatic sensitive devices!

Patent protected:
WO98/36395, DE 100 25 561, DE 101 50 128,
WO 2004/051591, DE 103 01 678 A1, DE 10309334,
WO 04/109236, WO 05/096482, WO 02/095707,
US 6,747,573, US 7,019,241

REVISION HISTORY

The following major modifications and improvements have been made to the first version of this document:

No	Major Changes
1.0	Initial Release for STM 400J
1.1	Added certification information and PCB Antenna description.
1.2	Small editorial review
2.0	Revision update & enhanced security mode added.
2.1	Update references and design
2.2	Update of ARIB regulations.

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Important!

This information describes the type of component and shall not be considered as assured characteristics. No responsibility is assumed for possible omissions or inaccuracies. Circuitry and specifications are subject to change without notice. For the latest product specifications, refer to the EnOcean website: http://www.enocean.com.

As far as patents or other rights of third parties are concerned, liability is only assumed for modules, not for the described applications, processes and circuits.

EnOcean does not assume responsibility for use of modules described and limits its liability to the replacement of modules determined to be defective due to workmanship. Devices or systems containing RF components must meet the essential requirements of the local legal authorities.

The modules must not be used in any relation with equipment that supports, directly or indirectly, human health or life or with applications that can result in danger for people, animals or real value.

Components of the modules are considered and should be disposed of as hazardous waste. Local government regulations are to be observed.

Packing: Please use the recycling operators known to you.

TABLE OF CONTENT

1   MODULE VARIANTS AND RELATED DOCUMENTS

This document describes the operation of STM 400J modules (based on the Dolphin V4 core) with their built-in firmware. If you want to write own firmware or need more detailed information, please also refer to:

- Dolphin V4 Core Description
- Dolphin API Documentation

In addition we recommend following our application notes, in particular:

- AN102: Antenna Basics – Basic Antenna Design Considerations for EnOcean based Products
- AN207: ECS 300/310 Solar Panel - Design Considerations
- AN208: Energy Storage – Design Considerations
- AN209: STM 300 THERMO OR BATTERY POWERED – Power Supply Alternatives to Solar Panel

With its firmware Dolphin V4 Universal Sensor Secured short: USN_S is an extension with encryption of the previous STM 400J – Universal Sensor Node.

2   GENERAL DESCRIPTION

2.1   Basic functionality

The extremely power saving RF transmitter module STM 400J of EnOcean enables the realization of wireless and maintenance free sensors and actuators such as room operating panels, motion sensors or valve actuators for heating control.

Power supply is provided by an external energy harvester, e.g. a small solar cell (e.g. EnOcean ECS 3x0) or a thermal harvester. An energy storage device can be connected externally to bridge periods with no supply from the energy harvester. A voltage limiter avoids damaging of the module when the supply from the energy harvester gets too high. The module provides a user configurable cyclic wake up. After wake up a radio telegram (input data, unique 32 bit sensor ID, checksum) will be transmitted in case of a change of any digital input value compared to the last sending or in case of a significant change of measured analogue values (different input sensitivities can be selected). In case of no relevant input change a redundant retransmission signal is sent after a user configurable number of wake-ups to announce all current values. In addition a wake up can be triggered externally.

EnOcean

Features with built-in firmware
- 3 A/D converter inputs
- 4 digital inputs
- Configurable wake-up and transmission cycle
- Wake-up via Wake pins
- Voltage limiter
- Threshold detector
- Application notes for calculation of energy budgets and management of external energy storages
- Encrypted communication
- EnOcean Equipment Profiles or Generic Profiles usage

Product variants
- STM 400J

Features accessible via API
Using the Dolphin API library it is possible to write custom firmware for the module. STM 400J is in-system programmable. The API provides:

- Integrated 16.384MHz 8051 CPU with 64 kB FLASH and 4 kB SRAM
- Receiver functionality
- Various power down and sleep modes down to typ. 100nA current consumption
- Up to 16 configurable I/Os
- 10 bit ADC, 8 bit DAC

2.2   Technical data

Antenna	External whip or 50 Ω antenna mountable
Frequency	928.35 MHz (FSK)
Data rate	125 kbps
Receiver Sensitivity (at 25 °C) only via API	typ. -95 dBm[1]
Conducted Output Power @ 50 Ohm	typ. 0 dBm
Power Supply	2.1 V–5 V, 2.6 V needed for start-up
Current Consumption	Deep Sleep mode : typ. 100 nA Transmit mode: typ. 22 mA Receive mode (via API only): typ. 27 mA
Input Channels	4x digital input, 2x WAKE input , 3x analog input Resolution: 3x 8 bit or 1x 10 bit, 1x 8 bit, 1x 6 bit
Radio Regulations	ARIB STD-T108

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[1] @ 0.1% telegram error rate (based on transmitted sub-telegrams)

2.3   Physical dimensions

PCB dimensions	22 x 19 x 3.1 mm
Weight	1.9 g

Unless otherwise specified dimensions are in mm.

Tolerances:
PCB outline dimensions ±0.2 mm
All other tolerances ±0.1 mm

STM 400J (pads on bottom side of PCB!)

2.4   Environmental conditions

Operating temperature	-25 °C … +85 °C
Storage temperature	-40 °C … +85 °C
Storage temperature in tape & reel package	-20 °C … +50 °C
Humidity	0% … 93% r.h., non-condensing

2.5   Ordering Information

Type	Ordering Code	Frequency
STM 400J	**S3061-D400**	**928.35 MHz**

Suited solar cells (for technical details please refer to the ECS3x0 data sheet):

Type	Ordering Code	Size
ECS 300	**S3005-D305**	**35.0 × 12.8 × 1.1 mm**
ECS 310	**S3005-D310**	**50.0 × 20.0 × 1.1 mm**

3 FUNCTIONAL DESCRIPTION

3.1 Simplified firmware flow chart and block diagram
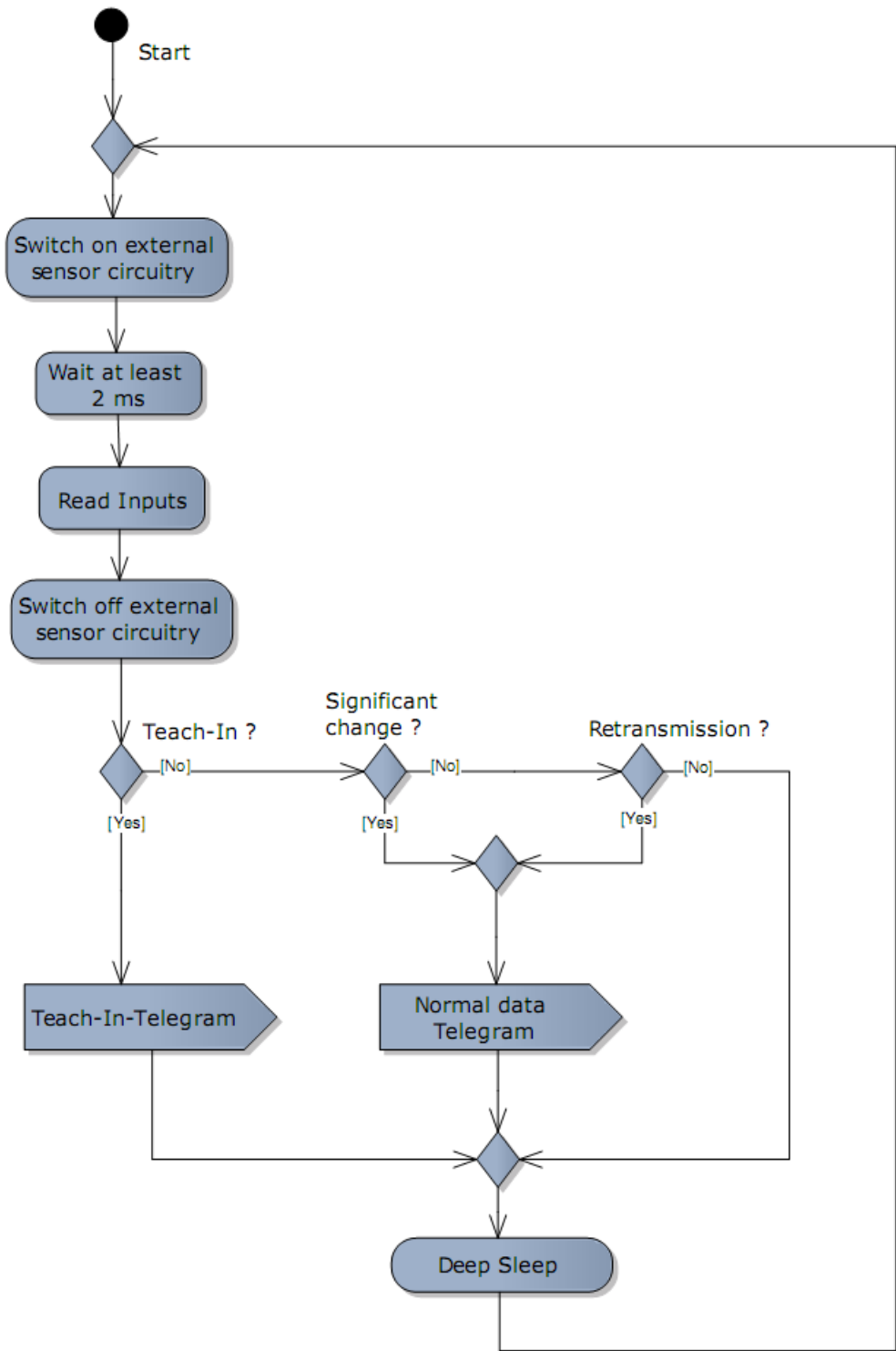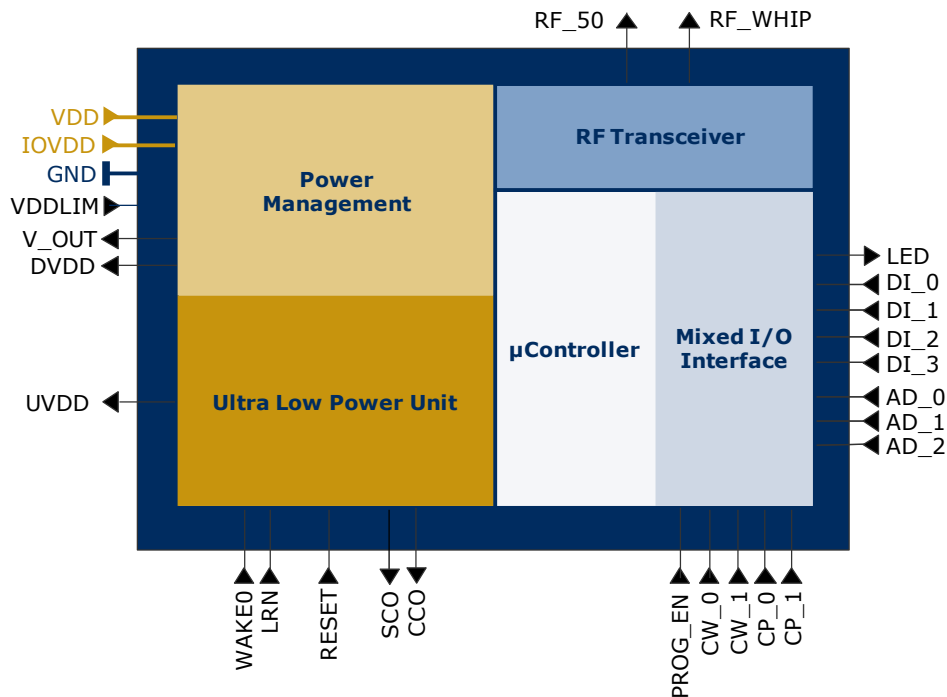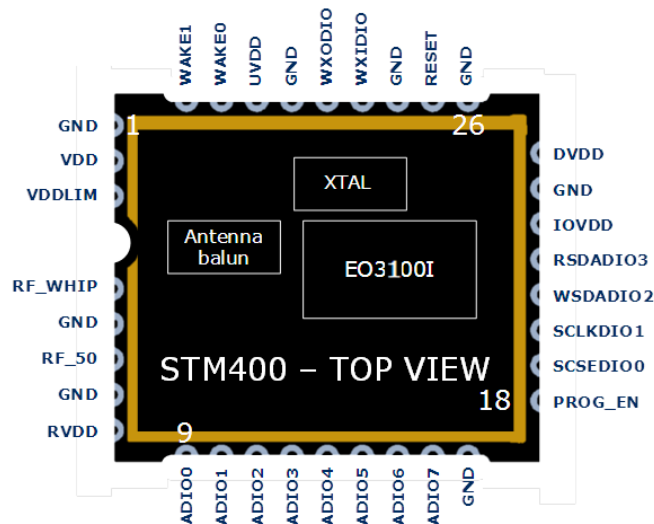
3.2 Hardware pin out

The figure above shows the pin out of the STM 400J hardware. The pins are named according to the naming of the Dolphin V4 core to simplify usage of the DOLPHIN API.

The table in section 3.3 shows the translation of hardware pins to a naming that fits the functionality of the built-in firmware. When writing own firmware based on the DOLPHIN API please refer to the Dolphin V4 Core Description and use this manual only for information regarding the module hardware, such as pin out, layout recommendations, charging circuitry, antenna options and approvals.

Difference to previous STM 400J version:

- Externall EEPROM can be conncted
- External configuration PINs are not available any more – CW / CP
- DIO 3 is not available any more

For power supply and technical datasheet please refer to the STM 400J User Manual.

Scavenger Transceiver Module
STM 400J

3.3 Pin description and operational characteristics

STM 400J Hardware Symbol	STM 400J pin #	STM 400J Firmware Symbol	Function	Characteristics
GND	1, 5, 7, 17, 24, 26, 28, 31	GND	Ground connection	Must be connected to GND
VDD	2	VDD	Supply voltage	2.1 V – 5.0 V; Start-up voltage: 2.6 V Maximum ripple: see 3.6
RVDD	8	V_OUT	RF supply voltage regulator output	1.8 V. Output current: max. 10 mA. See 0! Supply for external circuitry, available while not in deep sleep mode.
DVDD	25	DVDD	Digital supply voltage regulator output	1.8 V. Output current: max. 5 mA Supply for external circuitry, available while not in deep sleep mode.
UVDD	32	UVDD	Ultra low power supply voltage regulator output	Not for supply of external circuitry! For use with WAKE pins, see section 4.3. Max. 1 µA output current!
VDDLIM	3	VDDLIM	Supply voltage limiter input	Limitation voltage: 4.5 V Maximum shunting current: 50 mA
IOVDD	23	IOVDD	GPIO supply voltage	Must be connected to desired interface supply voltage as specified in 3.6, e.g. to DVDD. See also 3.4.1
RESET	27	RESET	Reset input Programming I/F	Active high reset (1.8 V) Connect external 10 kΩ pull-down.
PROG_EN	18	PROG_EN	Programming I/F	HIGH: programming mode active LOW: operating mode Digital input, connect external 10 kΩ pull-down.
ADIO0	9	AD_0	Analog input	Input read ~2 ms after wake-up. Resolution 8 bit (default) or 10 bit. See also 3.4.2.
ADIO1	10	AD_1	Analog input	Input read ~2 ms after wake-up. Resolution 8 bit (default) or 6 bit. See also 3.4.2.
ADIO2	11	AD_2	Analog input	Input read ~2 ms after wake-up. Resolution 8 bit. See also 3.4.2.
ADIO3	12	DI_0	Digital input	Input read ~2 ms after wake-up. See also 3.4.2.
ADIO4	13	DI_1	Digital input	Input read ~2 ms after wake-up. See also 3.4.2.
ADIO5	14	DI_2	Digital input	Input read ~2 ms after wake-up. See also 3.4.2.
ADIO6	15	DI_3	Digital input	Input read ~2 ms after wake-up.

				See also 3.4.2.
ADIO7	16	LED	Transmission indicator LED	Max. output current: 2 mA @ IOVDD=3.3 V 0.65 mA @ IOVDD=1.8 V
			Programming I/F	
SCSEDIO0	19	SDA	Data line for EEPROM.	Can be connected to external EEPROM to store the rolling code.
			Programming I/F	
SCLKDIO1	20	SLK	Clock line for EEPROM	Can be connected to external EEPROM to store the rolling code.
			Programming I/F	
WSDADIO2	21	N/A	N/A	N/A
			Programming I/F	
RSDADIO3	22	N/A	N/A	N/A
			Programming I/F	
WXIDIO	29	SCO	Sensor control	Digital output, max. current 15 µA HIGH ~x ms before analog inputs are read (x=0…508 ms; default 2 ms.) LOW at wake-up and after reading of analog inputs Polarity can be inverted, delay time can be programmed, see 3.10.
WXODIO	30	CCO	Charge control	Max output current 15 µA See 3.8 for description of behaviour.
WAKE0	33	WAKE0	Wake input	Change of logic state leads to wake-up and transmission of a telegram. See also 4.3.
WAKE1	34	LRN	LRN input	Change of logic state to LOW leads to wake-up and transmission of teach-in telegram if a manufacturer code is programmed. See also 4.3.
RF_WHIP	4	RF_WHIP	RF output	Output for whip antenna
RF_50	6	RF_50	RF output	50 Ohm output for external antenna

3.4 EEPROM Storage for the Rolling code

The Dolphin V4 Universal Sensor secured was developed to be used with external memory. We can refer to this possible EEPROM:

■ 24AA08 Microchip – 8 kilobit. See reference[2] for details.

As the Dolphin V4 Universal Sensor was developed using this module compatibility is guaranteed. Based on the characteristics of the EEPROM module they can be connected directly to the EnOcean Module.

The EEPROM must be connected to the SDA and SLK pins. The MEM_ACT pin controls the power supply of the EEPROM trough a MOS-FET (BSS223). You can connect the EEPROM

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[2] https://www.microchip.com/wwwproducts/en/24AA08

also directly to the power supply, but this way the EEPROM will consume a stand-by current (not recommended).

Please see example of EEPROM connection below:
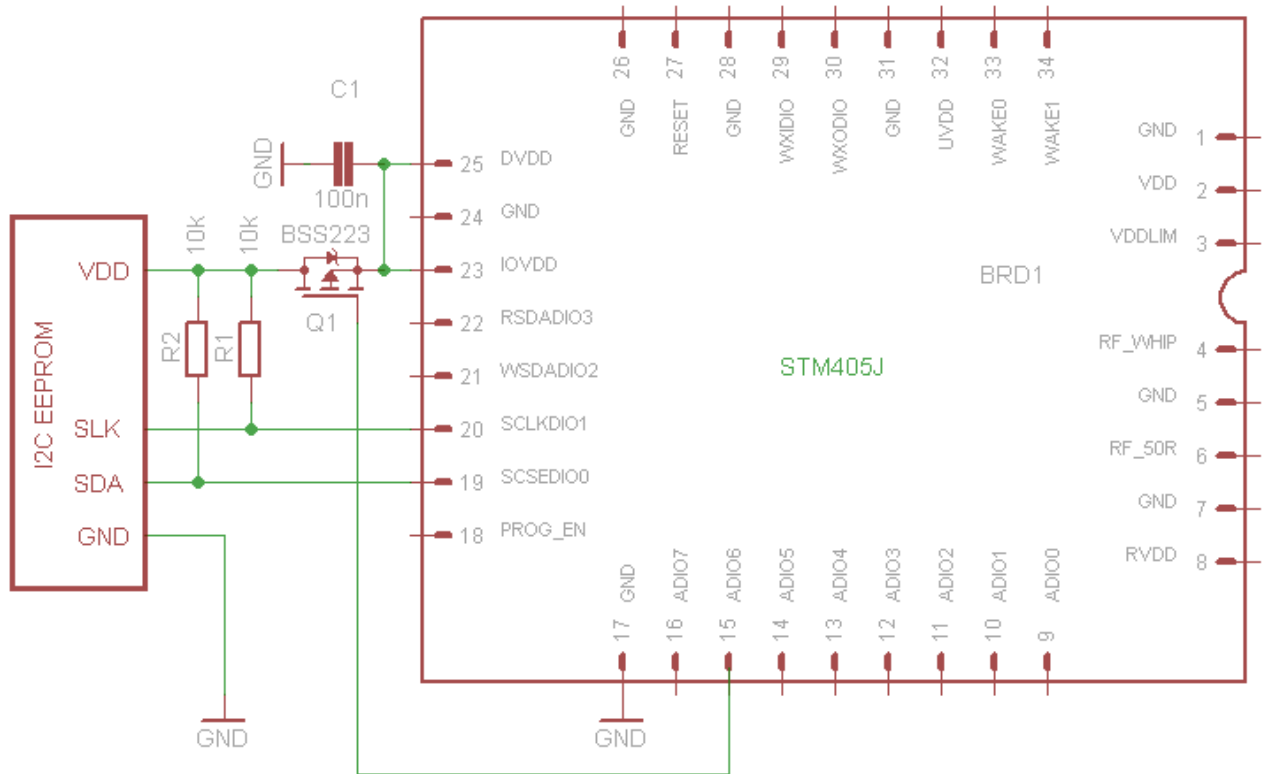
⚠️ Please check second source memory modules for compatibility before use. Changes in the Dolphin V4 Universal Sensor I2C interface may be required.

3.4.1 GPIO supply voltage

For digital communication with other circuitry (peripherals) the digital I/O configured pins of the mixed signal sensor interface (ADIO0 to ADIO7) and the pins of the programming interface (SCSEDIO0, SCLKDIO1, WSDADIO2, RSDADIO3) may be operated from supply voltages different from DVDD. Therefore an interface supply voltage pin IOVDD is available which can be connected either to DVDD or to an external supply within the tolerated voltage range of IOVDD. Please note that the wristwatch XTAL I/Os WXIDIO and WXODIO are always supplied from UVDD.

⚠ If DVDD=0 V (e.g. in any sleep mode or if VDD<VOFF) and IOVDD is supplied, there may be unpredictable and varying current from IOVDD caused by internal floating nodes. It must be taken care that the current into IOVDD does not exceed 10 mA while DVDD=0 V.
If DVDD=0 V and IOVDD is not supplied, do not apply voltage to any above mentioned pin. This may lead to unpredictable malfunction of the device.

⚠ For I/O pins configured as analog pins the IOVDD voltage level is not relevant! However, it is important to connect IOVDD to a supply voltage as specified in 3.4.2.
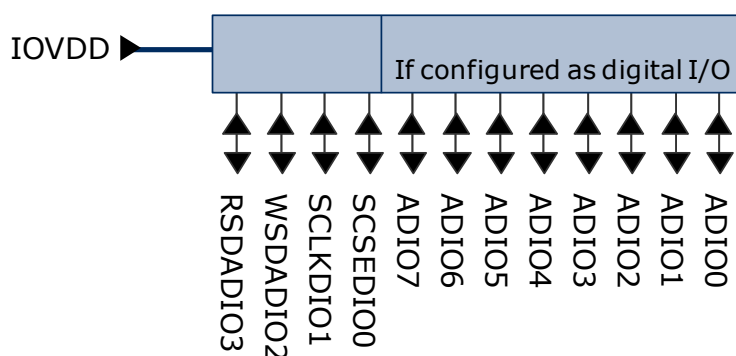
3.4.2 Analog and digital inputs

Parameter	Conditions / Notes	Min	Typ	Max	Units
Analog Input Mode					
Measurement range	Single ended Internal reference RVDD/2	0		RVDD	V
Input coupling			DC		
Measurement bandwidth			62.5		kHz
Input impedance	Single ended against GND @ 1 kHz	10			MΩ
Input capacitance	Single ended against GND @ 1 kHz			10	pF
Effective measurement resolution			10		Bit
10 bit measurement					
Offset error			5	10	LSB
Gain error			5	10	LSB
INL			2	4	LSB
DNL			0.5	1	LSB
8 bit measurement					
Offset error			1	2	LSB
Gain error			1	2	LSB
INL			0.5	1	LSB
DNL			0.125	0.25	LSB

Offset Error: Describes the offset between the minimal possible code and code 0x00.

Gain Error: Describes the offset between maximum possible code and full scale (e.g. 0x3FF for 10 bit measurements).

Integral Non-Linearity (INL): Describes the difference between the ideal characteristics and the real characteristics. Only values between minimum and maximum possible code are considered (excluding offset error and gain error).

Differential Non-Linearity (DNL): Measures the maximum deviation from the ideal step size of 1 LSB (least significant bit).

Effective resolution: Results from the signal-noise ratio of the ADC and is given in Bit. The number describes how many bits can be measured stable. The criterion selected here is that the noise of DNL is <±0.5 LSB.

Measurement Bandwidth: The measurement bandwitdh is internally limited by filters. A quasi static signal must be applied as long as the filter needs to settle. SettlingTime= 1/(MeasurementBandwidth)*ln(2^resolution[Bit])

Parameter	Conditions / Notes	Min	Typ	Max	Units
Digital Input Mode					
Input HIGH voltage		2/3 IOVDD			V
Input LOW voltage				1/3 IOVDD	V
Pull up resistor	@IOVDD=1.7 … 1.9 V	90	132	200	kΩ
	@IOVDD=3.0 … 3.6 V	38	54	85	kΩ

3.5 Absolute maximum ratings (non operating)

Symbol	Parameter	Min	Max	Units
VDD VDDLIM	Supply voltage at VDD and VDDLIM	-0.5	5.5	V
IOVDD	GPIO supply voltage	-0.5	3.6	V
GND	Ground connection	0	0	V
VINA	Voltage at every analog input pin	-0.5	2	V
VIND1	Voltage at RESET, WAKE0/1, and every digital input pin except WXIDIO/WXODIO	-0.5	3.6	V
VIND2	Voltage at WXIDIO / WXODIO input pin	-0.5	2	V

3.6 Maximum ratings (operating)

Symbol	Parameter	Min	Max	Units
VDD VDDLIM	Supply voltage at VDD and VDDLIM	VOFF	5.0	V
IOVDD	GPIO supply voltage (see also 3.3)	1.7	3.6	V
GND	Ground connection	0	0	V
VINA	Voltage at every analog input pin	0	2.0	V
VIND1	Voltage at RESET, WAKE0/1, and every digital input pin except WXIDIO / WXODIO	0	3.6	V
VIND2	Voltage at WXIDIO / WXODIO input pin	0	2.0	V

3.7 Power management and voltage regulators

Symbol	Parameter	Conditions / Notes	Min	Typ	Max	Units
Voltage Regulators						
VDDR	Ripple on VDD, where Min(VDD) > VON				50	mV$_{pp}$
UVDD	Ultra Low Power supply			1.8		V
RVDD	RF supply		1.7	1.8	1.9	V
DVDD	Digital supply		1.7	1.8	1.9	V
Voltage Limiter						
VLIM	Limitation voltage		4.0	4.5	5.5	V
ILIM	Shunting current				50	mA
Threshold Detector						
VON	Turn on threshold		2.3	2.45	2.6	V
VOFF	Turn off threshold	Automatic shutdown if VDD drops below VOFF	1.85	1.94	2.1	V

Voltage Limiter
STM 400J provides a voltage limiter which limits the supply voltage VDD of STM 400J to a value VDDLIM which is slightly below the maximum VDD ratings by shunting of sufficient current.

Threshold detector

STM 400J provides an ultra low power ON/OFF threshold detector. If VDD > VON, it turns on the ultra low power regulator (UVDD), the watchdog timer and the WAKE# pins circuitry. If VDD ≤ VOFF it initiates the automatic shut down of STM 400J.

3.8 Charge control output (CCO)

After start-up STM 400J provides the output signal of the threshold detector at CCO. CCO is supplied by UVDD. The output value remains stable also when STM 400J is in deep sleep mode.

Behaviour of CCO

- At power up: TRISTATE until VDD>VON then HIGH
- if VDD>VON then HIGH
- if VDD<VON then LOW
- if VDD< VOFF then LOW or TRISTATE
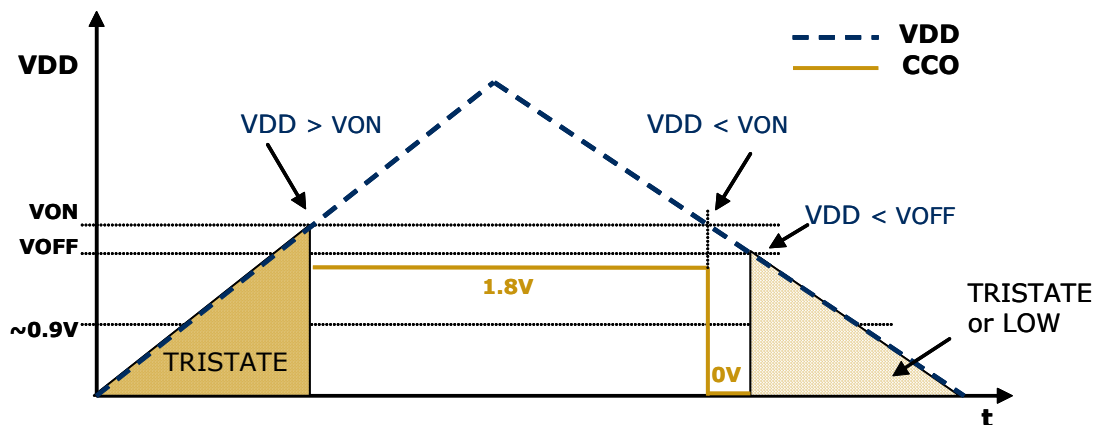
For definition of VON and VOFF please refer to 3.3.

3.9   Configuration

3.9.1 Configuration via pins – depreciated
Please consider that Configuration via PINs is not possible with STM 400J DB.

3.10   Configuration via programming interface

Via the programming interface the configuration area can be modified. This provides a lot more configuration options. Values set via programming interface override hardware settings! These settings are read after RESET or power-on reset only and not at every wake-up of the module!

The interface is shown in the figure below:

Parameter	Configuration via pins	Configuration via programming interface
Wake up cycle	See section 3.9.1	Value can be set from 1 s to 65534 s
Redundant Retransmission cycle	See section 3.9.1	Min…Max values for random interval If Min=Max -> random switched off
Threshold values for analog inputs	No	The default values are: 5 LSB at AD_1 input, 6 LSB at AD_0 and 14 LSB at AD_2. The threshold value can be set between 0 and full scale for every input individually.
Resolution of the analog inputs	No	Default: AD_0: 8 bit, AD_1: 8 bit, AD_2: 8 bit Option: AD_0: 10 bit, AD_1: 6 bit, AD_2: 8 bit
Input mask	No	A digital input mask for ignoring changes on digital input pins. At default all input bits are checked.
Delay time between SCO on and sampling moment	No	Value can be set from 0 ms to 508 ms in steps of 2 ms. Default delay time is 2 ms.
Source of AD_2	No	Select if AD_2 contains measurement value of external ADIO2 pin or from internal VDD/4
Polarity of SCO signal	No	Polarity can be inversed.
Edge of wake pin change causing a telegram transmission	No	Every change of a wake pin triggers a wake-up. For both wake pins it can be configured individually if a telegram shall be sent on rising, falling or both edges.
Manufacturer ID and EEP (EnOcean Equipment Profile)	No	Information about manufacturer and type of device. This feature is needed for "automatic" interoperability of sensors and actuators or bus systems. Information how to set these parameters requires an agreement with EnOcean. Unique manufacturer IDs are distributed by the EnOcean Alliance.

USB <=> SPI interface

Reset
PROG_EN
ADIO7
SCSEDIO0
SCLKDIO1
WSDADIO2

STM 400J

Dolphin V4 Suite, or EOPX2

EnOcean provides EOPX (EnOcean Programmer, a command line program) and Dolphin Studio (Windows application for chip configuration, programming, and testing) and the USB/SPI programmer device as part of the EDK 350 developer´s kit.

3.10.1   GP Configuration

Parameter	Configuration via programming interface
Used Communication profile.	What data communication profile is used. EEP or GP. Default is EEP.
Channel definition of AD_2	Data signal type definition of an analogue channel according the Generic Profiles definition. 4 data bytes describing the channel. Please look up the Generic Profiles description.
Channel definition of AD_1	Data signal type definition of an analogue channel according the Generic Profiles definition. 4 data bytes describing the channel. Please look up the Generic Profiles description.
Channel definition of AD_0	Data signal type definition of an analogue channel according the Generic Profiles definition. 4 data bytes describing the channel. Please look up the Generic Profiles description.
DI_2 & DI_1 & DI_0 channel definition	Flag signal type. DI_2 (first 1,5bytes), DI_1 (next 1,5bytes), DI_0 (next 1,5 bytes) together 4,5 bytes.

3.10.2   Security Configuration

Parameter	Configuration via programming interface
Secure mode	Selection if telegrams get additionally encrypted or not. Encryption is enabled when Enhanced Seecurity is selected. Default: Standard Security (not encrypted)
Mode Change	Defines if switch between standard and enhanced security mode with long press of LRN button is allowed or not. Default: Enabled.
External EEPROM Present	Default is set to yes. If set to no, then the module will not store the RLC. The Security level format must be specified not to use RLC, otherwise the RLC will restart after a power down.
Initialisation of external EEPROM.	One time option, must be performed at first start up. Default Yes.
SLF – Security Level Format	SLF (default=0x93): Bit7..6: RLC_ALGO. Bit5: RLC_Tx. Bit4..3: MAC_ALGO. Bit2..0: DATA_ENC. 0x93: 24-bit RLC, No RLC tx, 4-byte CMAC, VAES encryption Please refer to the Security specification for details on the Security level format.
Pre-shared key usage	Default: disabled.
Private Key	AES 128 key which is used for data encryption. Please refer to the Security specification for details on the Security level format.

Subkey 1	Subkey derivated from private key.
Subkey 2	Subkey derivated from private key.
Pre-shared Key	Pre-shared key used for PSK protected teach in.
Set initial RLC	Initial value of the RLC.

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3.11 Radio telegram structure

For exact radio telegram structure please refer to the EnOcean Radio Protocol 2 Specification - http://www.enocean.com/erp2/.

3.11.1 Link Layer Data (DATA_DL)

3.11.1.1 Link Layer Data (DATA_DL) for Normal Operation

Telegram content seen at programming interface of STM 400J or at DOLPHIN API:

RORG = 0xA5 (Telegram type "4BS")

Data_Byte1..3
3x8bit mode:
    DATA_BYTE3   = Value of AD_2 analog input
    DATA_BYTE2   = Value of AD_1 analog input
    DATA_BYTE1   = Value of AD_0 analog input

1x8bit, 1x6it, 1x10bit mode:
    DATA_BYTE3   = Value of AD_2
    DATA_BYTE2   = Upper 2 bits of AD_0 and value of AD_1
    DATA_BYTE1   = Lower 8 bits Value of AD_0 analog input

DATA_BYTE3								DATA_BYTE2						DATA_BYTE1								
AD_2								AD_1						AD_0								
7	6	5	4	3	2	1	0	5	4	3	2	1	0	9	8	7	6	5	4	3	2	1	0

DATA_BYTE0 = Digital input Status

Bit 7   Bit 0

Reserved, set to 0	DI_3	DI_2	DI_1	DI_0

    DI_3   = Status of digital input 3
    DI_2   = Status of digital input 2
    DI_1   = Status of digital input 1
    DI_0   = Status of digital input 0

The voltages measured at the analog inputs can be calculated from these values as follows:

$$U = (\text{Value of AD\_x})/(2^n) \times 1.8 \text{ V} \qquad n = \text{resolution of channel in bit}$$

3.11.1.2 Link Layer Data (DATA_DL) for Teach-in Telegrams

In case a manufacturer code is programmed into the module the module transmits – instead of transmitting a normal telegram – a dedicated teach-in telegram if

- digital input DI_3=0 at wake-up or
- wake-up via WAKE1 pin (LRN input)

With this special teach-in telegram it is possible to identify the manufacturer of a device and the function and type of a device. There is a list available from the EnOcean Alliance describing the functionalities of the respective products.

⚠️ If no manufacturer code is programmed the module does not react to signal changes on WAKE1 (LRN input)!

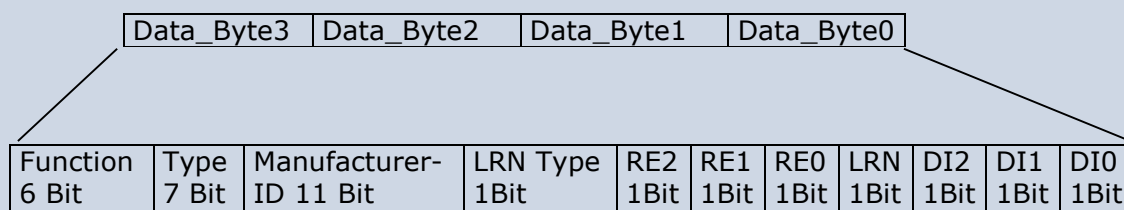RORG = 0xA5 (Telegram type "4BS")

DATA_BYTE0..3 see below
    Function, Type, Manufacturer-ID: Defined by manufacturer
    LRN Type = 1
    RE0..2: set to 0
    LRN = 0
    DI0..DI2: current status of digital inputs

Data_Byte3	Data_Byte2	Data_Byte1	Data_Byte0

Function 6 Bit	Type 7 Bit	Manufacturer-ID 11 Bit	LRN Type 1Bit	RE2 1Bit	RE1 1Bit	RE0 1Bit	LRN 1Bit	DI2 1Bit	DI1 1Bit	DI0 1Bit

3.12 Secure radio telegram

The STM 400J can be operated in:

- Standard mode – no enhanced security is used. This is the common operation mode, originally available. This is also the default factory mode.
- Security mode – communication is protected by enhanced security features. This mode was added later in module evolution.

3.12.1 Switching between modes

STM 400J can be switched from normal mode to secure mode and vice versa by long press of the LRN Button (Wake 1).

The behaviour of the LRN button is following:

1. Button is pressed – LED (ADIO7) flashes briefly Teach-in is performed according to the actual mode.
2. Button is hold

a. If released in period < 10 seconds then actual mode is kept. No further action.
b. If hold for at least 10 seconds then the actual mode is changed (standard -> secure or secure -> standard). LED flashes briefly. Teach-in is performed according to the actual (new) mode.
3. Button is released – no action.

Upon entry into secure mode, a secure teach-in telegram is sent by STM 400J.

⚠ Mode change features can be suppressed by configuration flag. If flag set module will not enter secure mode after long press, but stay in standard mode. By default mode change feature is enabled.

⚠ Before changing the operating mode please make sure to clear the device from all receivers which have been taught to work with this device before. Otherwise the receiver will ignore the telegrams and the application will not work.

⚠ The flag for actual mode itself is stored in non-volatile memory. After power down reset the previous selected mode is active. Therefore mode change is limited to 50 times. In normal application scenario only very few are required.

The factory delivery mode of the STM 400J is standard – not encrypted. This mode is common mode originally available. Secure mode was added in later product upgrades.

The mode change feature can be suppressed by a configuration parameter. By default mode change is enabled. For details on configuration please see chapter 3.10.2

3.12.2 Encrypted communication - Enhanced security mode

In enhanced mode the data link content is always protected with advanced security features. Normal operation DL and also Teach-in DL are protected in the same way. The security features used are configured by the Security Level format - SLF. This parameter is set by default to the highest possible level:

- 24-bit RLC,
- No RLC tx,
- 4-byte CMAC,
- VAES encryption

To change the SLF please refer to chapter 3.10.2.

To add security features to the communication the Normal operation DL and Teach-in DL are encapsulated into a secured telegram. The data content of the telegram is not changed. Please refer to the EnOcean Security Specification for details.

3.12.3 Security Teach-In - Enhanced security mode

To enable security communication the STM 400J has to send a security teach-in telegram to the other communication partner and so inform him about the used security profile, keys and initial RLC. The security teach-in has to take place before any other communication can be executed (profile teach-in included). To trigger the transmission of the teach-in telegram WAKE1 pin (LRN input) is pressed. The security teach-in telegram is transmitted before the profile teach-in. The following profile teach-in telegram is already protected by advanced security features.

The process of sending security teach-in telegram and profile teach-in telegram is triggered by one pressing of the LRN button.

The behaviour of the LRN button in enhanced mode is following:
1. Button is pressed
2. Security teach-in is send.
3. Profile teach-in is send.

3.12.3.1 PSK Security Teach-in - Enhanced security mode - optional

The Security Teach-in telegram carries the information of KEY and RLC. This information is either send plain text (as is) or it is protected by the pre-shared key - PSK. The PSK must be in printed on the transmitting device. To use PSK teach-in, the PSK must be read by the end-user and entered into the other communication partner. For this purpose the EnOcean radio interface cannot be used. The PSK can be entered via an user interface or by semi-automatized by a code reader.

For details on the PSK Teach-in please refer to the EnOcean Security Speification.

PSK feature is disabled by default. To enable PSK feature the execute configuration via programming interface. See chapter 3.10.2 for details.

3.13   Transmit timing

The setup of the transmission timing allows avoiding possible collisions with data packages of other EnOcean transmitters as well as disturbances from the environment. With each transmission cycle, 3 identical subtelegrams are transmitted within 25 ms. Transmission of a subtelegram lasts approximately 1.2 ms. The delay time between the three transmission bursts is affected at random.

⚠️ If a new wake-up occurs before all sub-telegrams have been sent, the series of transmissions is stopped and a new series of telegrams with new valid measurement values is transmitted.

3.14   Energy consumption

Typical Current Consumption of STM 400J during TX

Charge needed for one measurement and transmit cycle: ~130 µC
Charge needed for one measurement cycle without transmit: ~30 µC
(current for external sensor circuits not included)

Calculations are performed on the basis of electric charges because of the internal linear voltage regulator of the module. Energy consumption varies with voltage of the energy storage while consumption of electric charge is constant.
From these values the following performance parameters have been calculated:

Without Enhanced Security

Wake cycle [s]	Transmit interval	Operation Time in darkness [h] when storage fully charged	Required reload time [h] at 200 lux within 24 h for continuous operation	24 h operation after 6 h illumination at x lux	Illumina-tion level in lux for continuous operation	Current in µA required for con-tinuous operation
1	1	0.5	storage too small	storage too small	5220	130.5
1	10	1.7	storage too small	storage too small	1620	40.5
1	100	2.1	storage too small	storage too small	1250	31.3
10	1	5.1	storage too small	storage too small	540	13.5
10	10	16	21	storage too small	175	4.4
10	100	20	16.8	storage too small	140	3.5
100	1	43	7.8	260	65	1.6
100	10	98	3.6	120	30	0.8
100	100	112	3	100	25	0.6

Consumption with EEPROM (with RLC) and security

Wake cyc-le[s]	Transmit interval	Operation Time in darkness [h] when storage fully charged	Required reload time [h] at 200 lux within 24 h for continuous operation	24h operation after 6h illumi-nation at x lux	Illumina-tion level in lux for continuous operation	Current in µA required for con-tinuous operation
1	1	0,4	Storage too small	Storage too small	8013	180
1	10	1,5	Storage too small	Storage too small	2013	45
1	100	2,2	Storage too small	Storage too small	1413	32
10	1	4	Storage too small	Storage too small	813	18,30
10	10	14	26	Storage too small	213	4,80
10	100	20	18	Storage too small	153	3,45
100	1	33	11	373	93	2,10
100	10	93	4	133	33	0,75
100	100	113	3	109	27	0,62

Assumptions:
- Storage PAS614L-VL3 with 0.25 F, Umax=3.2 V, Umin=2.2 V, T=25°C
- Consumption: Transmit cycle 100 µC, measurement cycle 30 µC
- Indoor solar cell, operating values 3 V and 5 µA @ 200 lux fluorescent light (e.g. ECS 300 solar cell)
- Current proportional to illumination level (not true at very low levels!)

These values are calculated values, the accuracy is about +/-20%!

4 APPLICATIONS INFORMATION

4.1 How to connect an energy harvester and energy storage

STM 400J is designed for use with an external energy harvester and energy storage.
In order to support a fast start-up and long term operation with no energy supply available usually two different storages are used. The small storage fills quickly and allows a fast start-up. The large storage fills slowly but once it is filled up it provides a large buffer for times where no energy is available, e.g. at night in a solar powered sensor.
STM 400J provides a digital output CCO (see also 3.8) which allows controlling the charging of these two storages. At the beginning, as long as the voltage is below the VON voltage only the small storage is filled. Once the threshold is reached the CCO signal changes and the large storage is filled. The short term storage capacitor (C1) is usually in the range of 470 to 1000 µF. For the long term storage we suggest a capacitor (C2) with a capacity of 250mF. Below an overview and the schematics of a charging circuitry is shown:
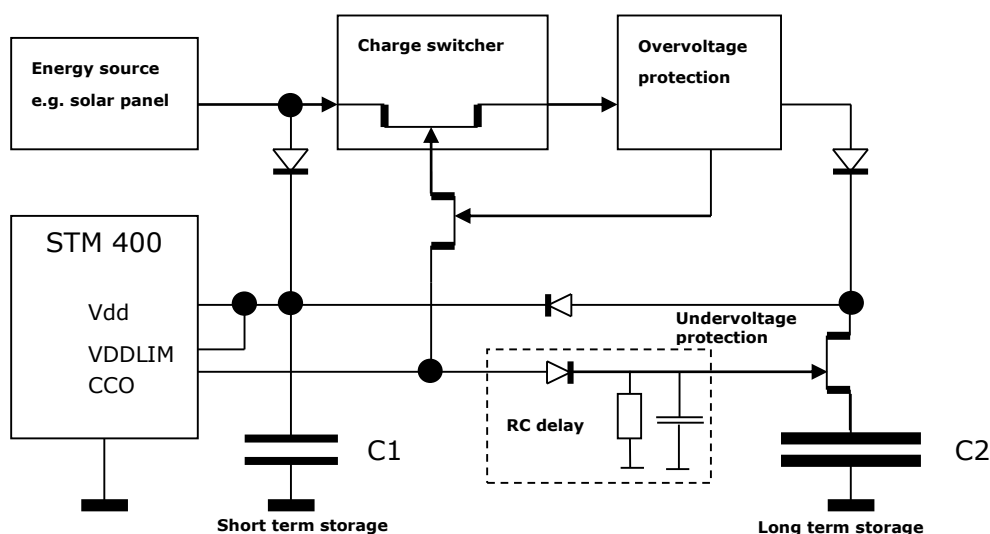
This circuit is designed for an energy storage capacitor specified for 3.3 V (e.g. PAS614L-VL3. Please pay great attention to manufacturers handling and soldering procedures!)

EnOcean
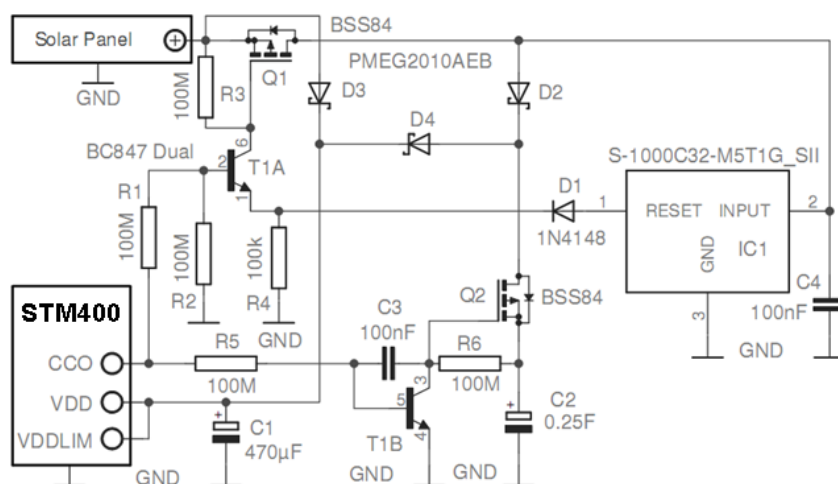
Charge switcher

The charge switcher connects both short term storage and long term storage parallel to the energy source as soon as the STM 400J supply voltage reaches the typical VON threshold of 2.45 V. Supposing VDD then falls below VON, the energy source will be switched back to short term storage alone, for faster recharging. As long as the voltage on long term storage remains below VON, the charge switcher will continuously switch the energy source between short term and long term storage, trying to ensure continuous device operation. That is because of the higher resistance and capacitance of long term storage, which would lead to much too long charging (i.e. non-operative time). In addition short term storage cannot be charged over this threshold until the voltage on long term storage exceeds VON. Charge switcher is the PMOS transistor Q1, driven from the STM 400J charge control output CCO over T1A. To start with, as long as the STM 400J VDD voltage is below the VON threshold, only the small storage (C1) is filled over D3. Once the threshold is reached, the CCO control signal goes High, T1B and Q2 are turned on and the long term storage (C2) will be filled over Q2.

Overvoltage protection

All of these long term storage solutions have a rated operating voltage that must be not exceeded. After reaching this limit the energy source is automatically separated from storage to avoid any damage. Overvoltage protection is implemented by the S-1000C32-M5T1x voltage detector from Seiko (SII) or the NCP300LSN30T1G series (ON Semiconductor), which limits the maximum charging voltage to 3.3 V to avoid damaging long term energy storage. In case a different voltage limit is required, this device has to be replaced by a suitable voltage variant. As soon as the voltage on D2 anode or the voltage detector input exceeds the selected threshold, the voltage detector delivers a High level on its output connected to the T1A emitter. The T1A base is consequently lower polarized than its emitter and the transistor is turned off. That means Q1 is turned off too — the energy source is switched off and long term storage is protected.

The selected voltage detector must have a very low quiescent current in the operating range, and an appropriate threshold voltage, corresponding to the selected long term energy storage voltage (e.g. threshold nominally 3.2 V for a 3.3 V capacitor). If the selected threshold is too low, e.g. 3.0 V, a relatively high amount of energy corresponding to a useful voltage difference of 0.3 V would be wasted. If the nominal threshold is too high, e.g. exactly 3.3 V (not forgetting that this could reach 3.4 V as a result of additional manufacturer tolerances), it could be critical for energy storage life expectation. The S-1000C32-M5T1x voltage detector consequently looks like the best compromise here (rated 3.2 V)

Undervoltage protection

PAS capacitors should not be deep discharged to voltages below 1.5 V. To avoid long term degradation of their capacity and lifetime, an undervoltage protection block is added. Undervoltage protection is also implemented through Q2. In normal operation, when VDD reaches the VON threshold, the STM 400J charge control CCO goes high, T1B rapidly discharges C3 to GND and Q2 turns on long term storage. The C3 charge recovers very slowly over R6, so Q2 cannot turn off long term storage immediately. Only if VDD falls below VOFF for a longer time does C3 have time to recover and finally to turn off Q2 and thus the long term storage path (over D4) from the STM 400J, avoiding deep discharge.

For more details and alternative circuits please refer to application note AN208.

4.2 Using the SCO pin

STM 400J provides an output signal at SCO which is suited to control the supply of the sensor circuitry. This helps saving energy as the sensor circuitry is only powered as long as necessary. In the default configuration SCO provides a HIGH signal 2 ms (delay time) before the analog inputs are read. Via the programming interface (see 3.10) it is possible to adjust the delay time and also the polarity of the signal.
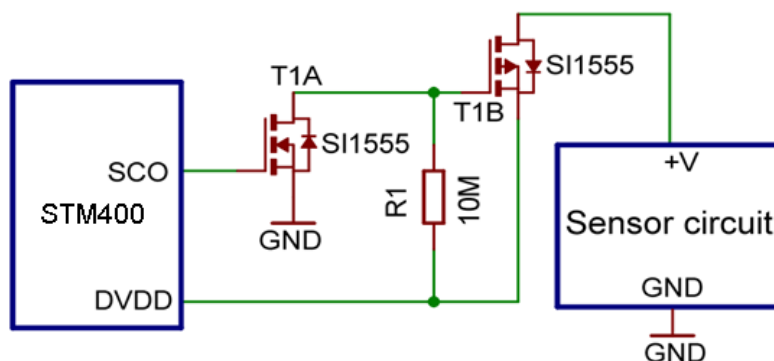
The figure above shows, how the SCO pin (with default polarity) can be used to control an external sensor circuit.

⚠ Do not supply sensors directly from SCO as this output can only provide maximum 15 µA!

4.3 Using the WAKE pins

The logic input circuits of the WAKE0 and WAKE1 pins are supplied by UVDD and therefore also usable in "Deep Sleep Mode" or "Flywheel Sleep Mode" (via API only). Due to current minimization there is no internal pull-up or pull-down at the WAKE pins.
When STM 400J is in "Deep Sleep Mode" or "Flywheel Sleep Mode" (via API only) and the logic levels of WAKE0 and / or WAKE1 is changed, STM 400J starts up.

⚠ As the there is no internal pull-up or pull-down at the WAKE pins, it has to be ensured by external circuitry, that the WAKE pins are at a defined logic level at any time.

⚠ When using the UVDD regulator output as source for the logic HIGH of the WAKE pins, it is strongly recommended to protect the ultra low power UVDD voltage regulator against (accidental) excessive loading by connection of an external 1.8 MΩ series resistor.
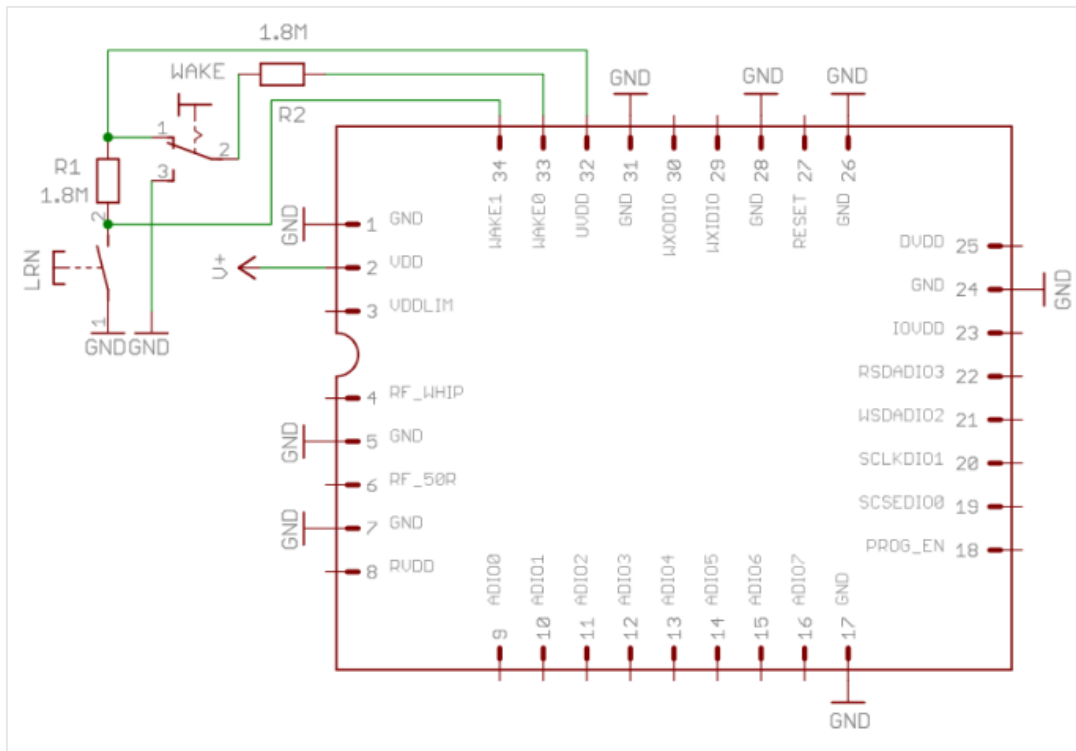
The figure above shows two examples how the WAKE inputs may be used. When the LRN
button is pressed WAKE1 is pulled to GND and a teach-in telegram is transmitted.
As long as the button is pressed a small current is flowing from UVDD to GND.
WAKE0 is connected to a toggle switch. There is no continuous flow of current in either po-
sition of the switch.

If more digital inputs with WAKE functionality are needed in an application, WAKE0 can be
combined with some of the digital inputs as shown below:
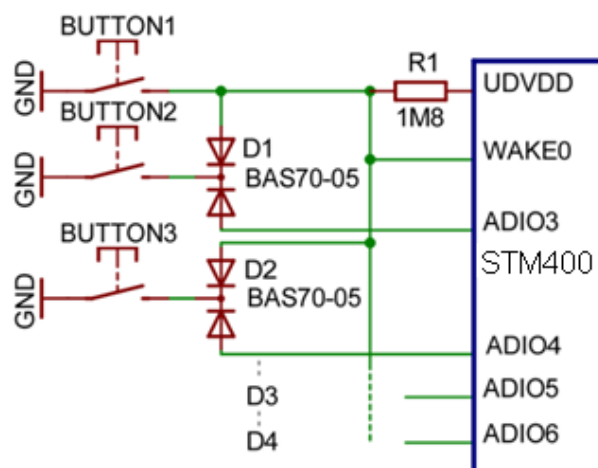
4.4   Using RVDD

If RVDD is used in an application circuit a serial ferrite bead shall be used and wire length should be as short as possible (<3 cm). The following ferrite beads have been tested: 74279266 (0603), 74279205 (0805) from Würth Elektronik. During radio transmission and reception only small currents may be drawn (I<100 µA).
Pulsed current drawn from RVDD has to be avoided. If pulsed currents are necessary, sufficient blocking has to be provided.

4.5   Antenna options for STM 400J

4.5.1 Overview

Several antenna types have been investigated by EnOcean. Please refer to our application notes AN102, and AN105 which give an overview on our recommendations.
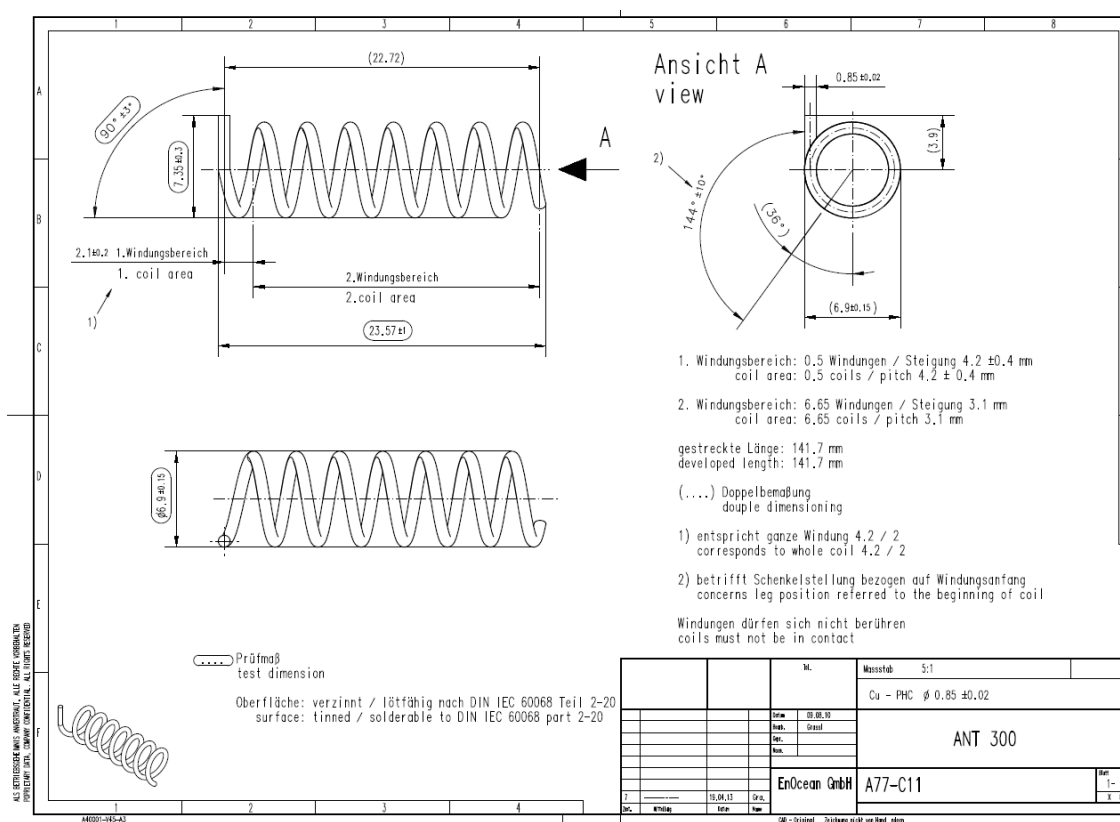
4.5.2 Whip antenna

928.35 MHz
Antenna: 64 mm wire, connect to RF_WHIP
Minimum GND plane: 50 mm x 50 mm
Minimum distance space: 10 mm

4.5.3 Helical antenna

928.35 MHz
according to drawing below, connect to RF_WHIP
Minimum GND plane: 35 mm x 30 mm
Minimum distance space: 10 mm

4.5.4 Top loaded PCB spiral antenna

The design of the antenna made on a 1mm thick, two layer FR4 PCB. The dimensions are given in figure below. The hatched areas are double sided in layout. The large area to the left is a ground area. Components can be placed here as long as the area is not split by this nor has long cuts in it which can act as radiators its self.
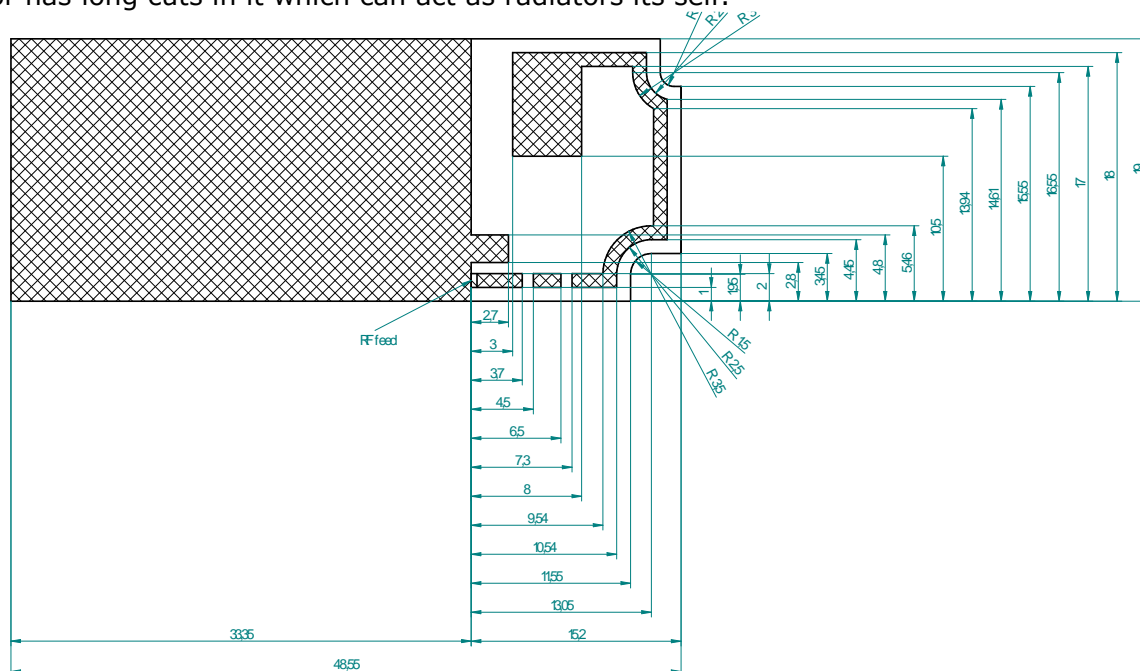

Dimensions of the PCB antenna.

Parameter of PCB	VALUE
PCB material	FR4, 2 layer
Thickness (total)	1,27mm
Shape	Rectangular with millings
Dimension	19*48,55 mm

Layer	Thickness in µm	Exact description
Solder Mask		Solder resist
Top Layer	35	Cu, >35um after electroplating
Core	1200	
Bottom Layer	35	Cu, >35um after electroplating
Solder Mask		Solder resist
Total	1270	

The PCB antenna uses three discrete matching components. The position of these components can be seen in figure below.
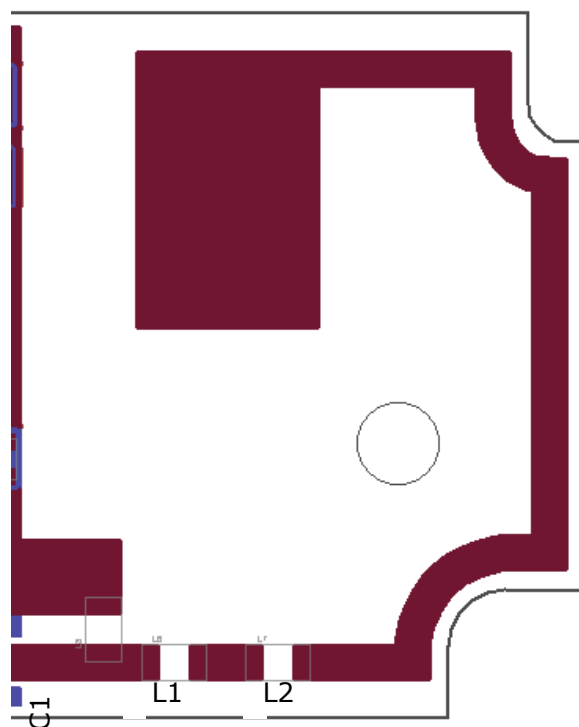
Position of matching components

The antenna was matched to 50Ω input impedance at the feed point. A compromise for a good matching when plugged into a laptop and when plugged to the end of a USB cable was chosen. Several environments in the proximity of the antenna where also evaluated for this compromise. The following table shows the values of the proposed components.

Component	Value
C1	3.3pF
L1	12nH
L2	12nH

0603 components where used for the antenna matching. For the capacitor general purpose C0G capacitors with 5% tolerance are sufficient. The inductors should be wire wound inductors from the Würth WE-KI series or the Murata LQW series.

4.6   Positioning of the whip antenna

Positioning and choice of receiver and transmitter antennas are the most important factors in determining system transmission range.

For good receiver performance, great care must be taken about the space immediately around the antenna since this has a strong influence on screening and detuning the antenna. The antenna should be drawn out as far as possible and must never be cut off. Mainly the far end of the wire should be mounted as far away as possible (at least 15 mm) from all metal parts, ground planes, PCB strip lines and fast logic components (e.g. microprocessors).
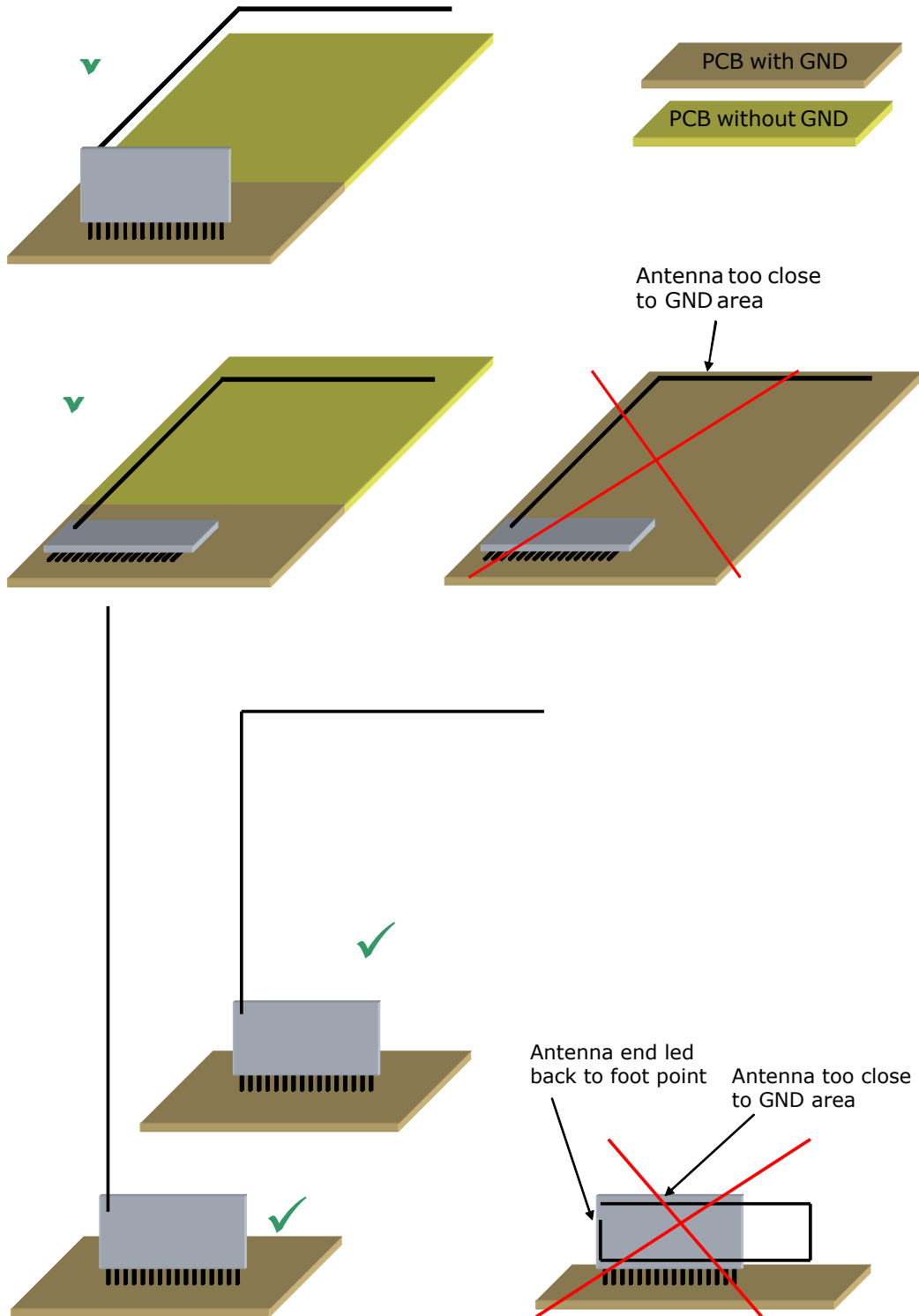Do not roll up or twist the whip antenna!

Radio frequency hash from the motherboard desensitizes the receiver. Therefore:

- PCB strip lines on the user board should be designed as short as possible
- A PCB ground plane layer with sufficient ground vias is strongly recommended

4.7 Recommendations for laying a whip antenna

PCB with GND

PCB without GND

Antenna too close
to GND area

Antenna end led
back to foot point

Antenna too close
to GND area

4.8   Layout recommendations for foot pattern

⚠ The length of lines connected to I/Os should not exceed 5 cm.

⚠ It is recommended to have a complete GND layer in the application PCB, at least in the area below the module and directly connected components (e.g. mid-layer of your application PCB).

Due to unisolated test points there are live signals accessible on the bottom side of the module.

Please follow the following advices to prevent interference with your application circuit:

- We suggest avoiding any copper structure in the area directly underneath the module (top-layer layout of your application PCB). If this is not possible in your design, please provide coating on top of your PCB to prevent short circuits to the module. All bare metal surfaces including vias have to be covered (e.g. adequate layout of solder resist).

- It is mandatory that the area marked by the circle in the figure below is kept clear of any conductive structures in the top layer and 0.3 mm below. Otherwise RF performance will be degraded!
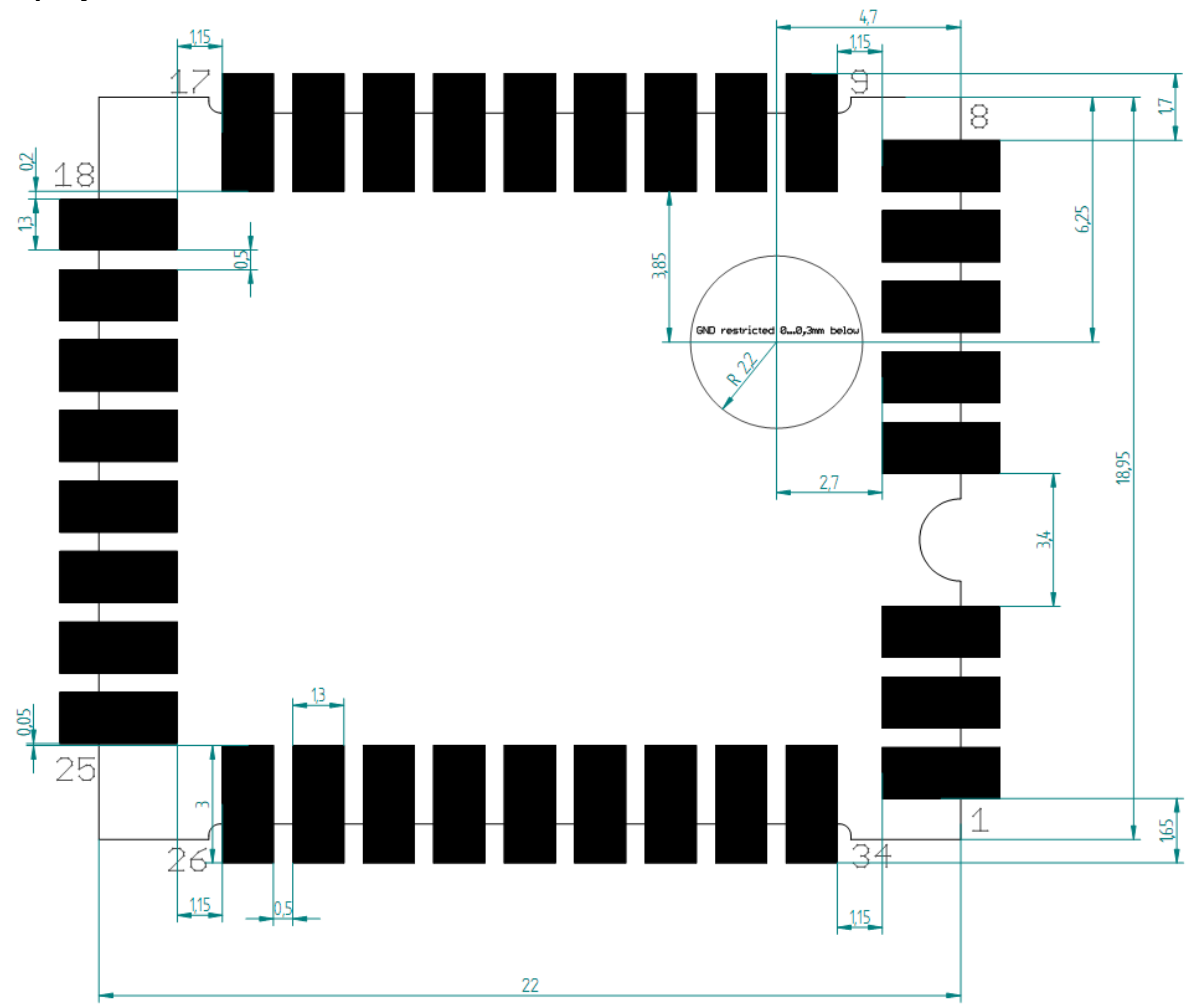
Furthermore, any distortive signals (e.g. bus signals or power lines) should not be routed underneath the module. If such signals are present in your design, we suggest separating them by using a ground plane between module and these signal lines.

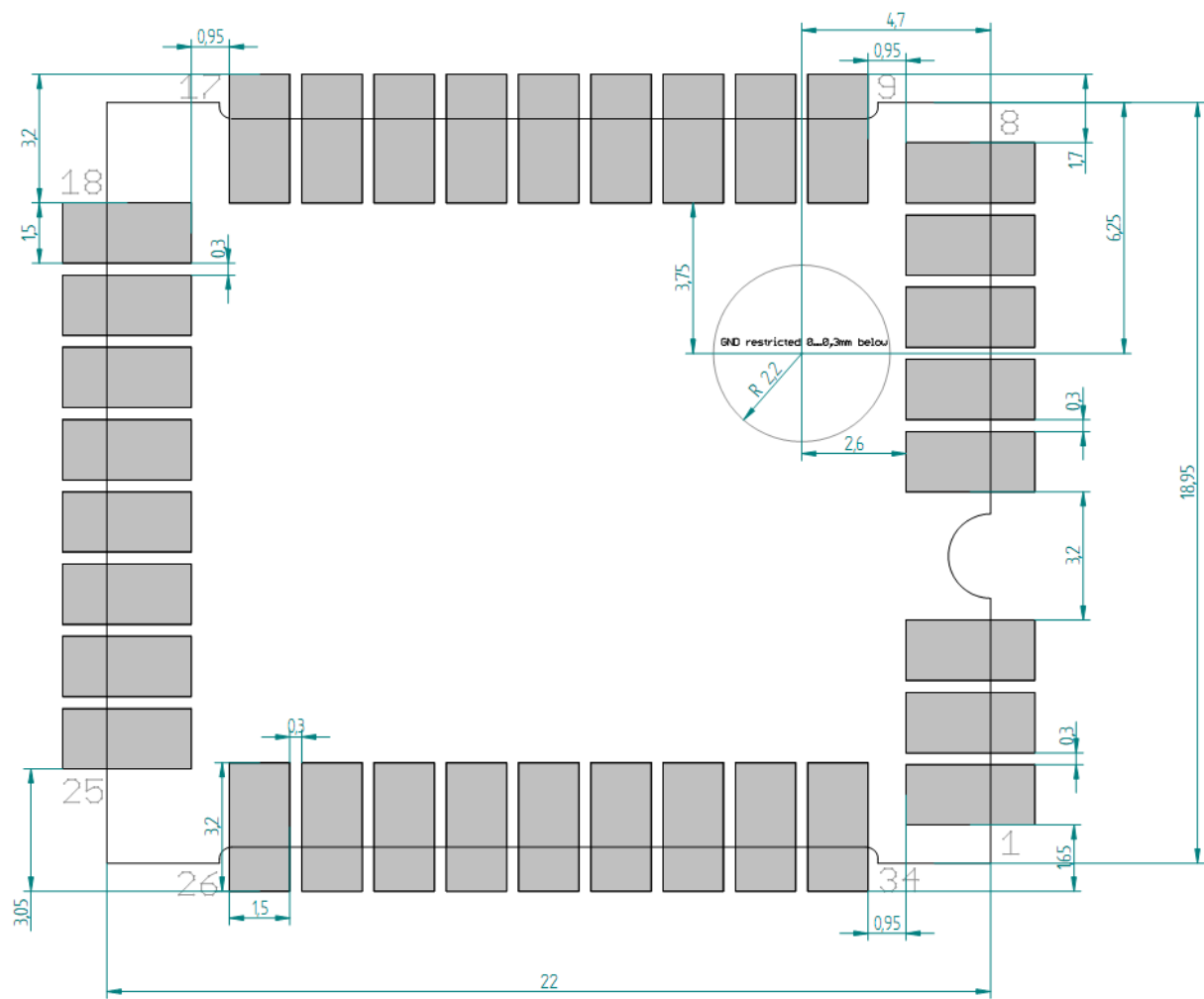⚠ The RVDD line should be kept as short as possible. Please consider recommendations in section 0.

Top layer

Solder resist top layer

Solder paste top layer
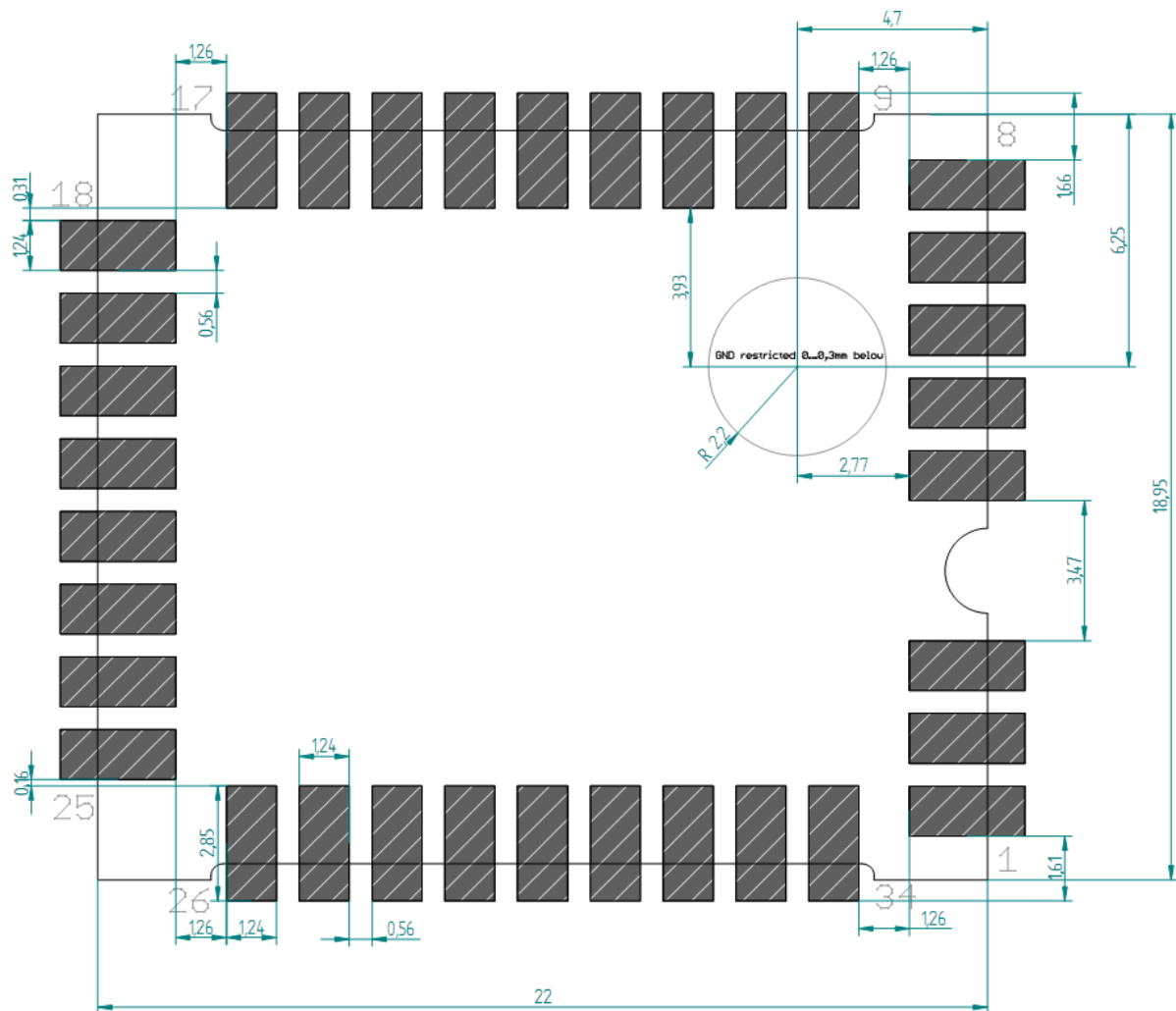
The data above is also available as EAGLE library.

In order to ensure good solder quality a solder mask thickness of 150 µm is recommended.

In case a 120 µm solder mask is used, it is recommended to enlarge the solder print. The pads on the solder print should then be 0.1 mm larger than the pad dimensions of the module as specified in chapter 2.3. (not relative to the above drawing).

Nevertheless an application and production specific test regarding the amount of soldering paste should be performed to find optimum parameters.

4.9   Soldering information

STM 400J has to be soldered according to IPC/JEDEC J-STD-020C standard.

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Ts_{max} to Tp)	3° C/second max.
Preheat – Temperature Min (Ts_{min}) – Temperature Max (Ts_{max}) – Time (ts_{min} to ts_{max})	150 °C 200 °C 60-180 seconds
Time maintained above: – Temperature (T_L) – Time (t_L)	217 °C 60-150 seconds
Peak/Classification Temperature (Tp)	260 °C
Time within 5 °C of actual Peak Temperature (tp)	20-40 seconds
Ramp-Down Rate	6 °C/second max.
Time 25 °C to Peak Temperature	8 minutes max.

Note 1: All temperatures refer to topside of the package, measured on the package body surface.
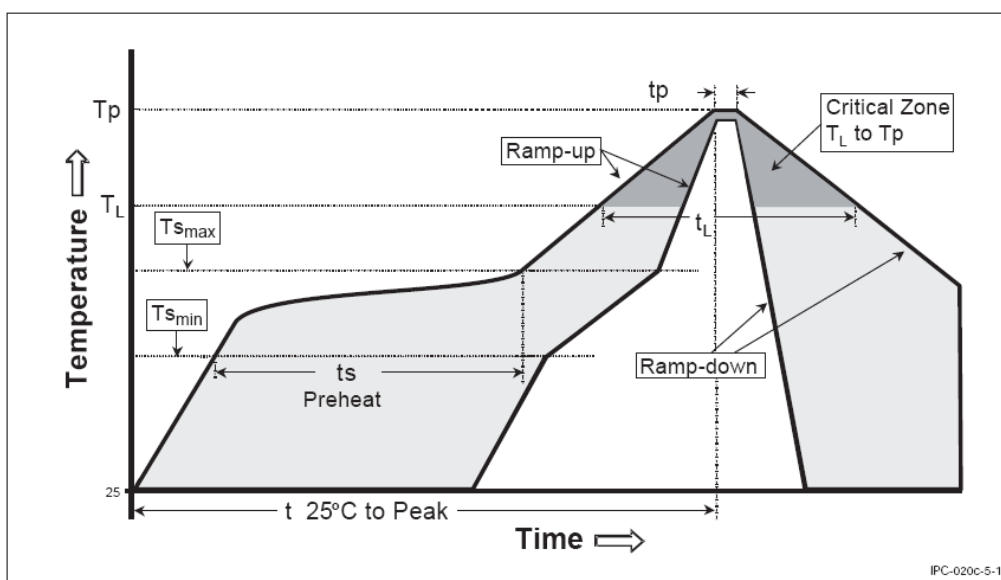
STM 400J shall be handled according to Moisture Sensitivity Level MSL4 which means a floor time of 72 h. STM 400J may be soldered only once, since one time is already consumed at production of the module itself.

Once the dry pack bag is opened, the desired quantity of units should be removed and the bag resealed within two hours. If the bag is left open longer than 30 minutes the desiccant should be replaced with dry desiccant. If devices have exceeded the specified floor life time of 72 h, they may be baked according IPC/JEDEC J-STD-033B at max. 90°C for less than 60 h.

Devices packaged in moisture-proof packaging should be stored in ambient conditions not exceeding temperatures of 40 °C or humidity levels of 90% r.h.

STM 400J modules have to be soldered within 6 months after delivery!

4.10   Tape & Reel specification

Tape running direction

4.11   Transmission range

The main factors that influence the system transmission range are type and location of the antennas of the receiver and the transmitter, type of terrain and degree of obstruction of the link path, sources of interference affecting the receiver, and "Dead" spots caused by signal reflections from nearby conductive objects. Since the expected transmission range strongly depends on this system conditions, range tests should categorically be performed before notification of a particular range that will be attainable by a certain application.

The following figures for expected transmission range may be used as a rough guide only:

- Line-of-sight connections: Typically 30 m range in corridors, up to 100 m in halls
- Plasterboard walls / dry wood: Typically 30 m range, through max. 5 walls
- Line-of-sight connections: Typically 30 m range in corridors, up to 100 m in halls
- Ferroconcrete walls / ceilings: Typically 10 m range, through max. 1 ceiling
- Fire-safety walls, elevator shafts, staircases and supply areas should be considered as screening.

The angle at which the transmitted signal hits the wall is very important. The effective wall thickness – and with it the signal attenuation – varies according to this angle. Signals should be transmitted as directly as possible through the wall. Wall niches should be avoided. Other factors restricting transmission range:

- Switch mounted on metal surfaces (up to 30% loss of transmission range)
- Hollow lightweight walls filled with insulating wool on metal foil
- False ceilings with panels of metal or carbon fiber
- Lead glass or glass with metal coating, steel furniture

The distance between EnOcean receivers and other transmitting devices such as computers, audio and video equipment that also emit high-frequency signals should be at least 0.5 m

A summarized application note to determine the transmission range within buildings is available as download from www.enocean.com.

5   AGENCY CERTIFICATIONS

The modules have been tested to fulfil the approval requirements based on the built-in firmware.

⚠️ **When developing customer specific firmware based on the API for this module, special care must be taken not to exceed the specified regulatory limits, e.g. the duty cycle limitations!**

Please find more details in the EnOcean Radio Protocol 2 Specification[3].

5.1   Japanese Type Approval

TCM 410J complies with the Japanese radio law and is certified according to ARIB STD-T108.

When the product is placed on the Japanese market, it must carry the Specified Radio Equipment marking as shown below:

Ⓡ 206-000372

If the certification label cannot be recognized from outside (e.g. installation in a host) appropriate information must be referenced in the user manual.

---

[3] https://www.enocean.com/fileadmin/redaktion/pdf/tec_docs/EnOceanRadioProtocol2.pdf

EMCC™ DR. RAŠEK

Notified Body Directive 99/5/EC
Notified Body EMC Directive 2004/108/EC
RF CAB under the Japan-EC MRA
FCB under the Canada-EC MRA
TCB under the USA-EC MRA

RF CAB ID No. 206

Designated by the German Regulator Bundesnetzagentur to act as a
Recognised Foreign Conformity Assessment Body in accordance with the Japan-EC MRA

CONSTRUCTION TYPE CONFORMITY CERTIFICATE
for
Specified Radio Equipment

Registration No.	JU000372D
Certificate Holder	EnOcean GmbH Kolpingring 18a 82041 Oberhaching Germany
Product Category	Article 2, Paragraph 1, Item 8 (Y)
Product Designation	STM 400J, TCM 410J, USB 400J
Product Description	Scavenger Transceiver Module, Transceiver Module, USB Gateway
Software Release No.	--
Manufacturer	Katek GmbH Bahnhofstraße 108 83224 Grassau Germany

When the product is placed on the
Japanese market, it must carry the
Specified Radio Equipment marking
as shown on the right

R 206-000372

The scope of evaluation relates to the submitted documents only.

This Certificate confirms that the listed product has demonstrated conformity with the relevant
technical regulations defined in the attached Annex. It is only valid in conjunction with the Annex.

Unterleinleiter,
2013-08-09

Klaus Knörig
Recognised Foreign Conformity Assessment Body

EMCCert DR. RAŠEK GmbH • Stoernhofer Berg 15, 91364 Unterleinleiter, Germany
Tel.: +49-9194-72279-01 • Fax: +49-9194-72279-06 • E-mail: emc.cert@emcc.de • Web: www.emcc.de

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Annex to Certificate Registration No. JU000372D
Date 2013-08-09
Page 1 of 1

Technical Construction File (TCF) Details

Technical Standards and Specifications

The product complies with:
Ordinance Regulating Radio Equipment (Radio Regulatory commission No.18, 1950)

Chapter I	General Provisions
Chapter II	Transmitting Equipment
Chapter III	Receiving Equipment
Chapter IV	Article 49.14

Documentation submitted for the Type Certification

Test Report No.	Issue Date	Issued by
EMCC-110010CC	2013-07-10	EMCCons DR. RAŠEK GmbH & Co. KG

Product documentation
Antenna specifications
Block diagram
Component layout
Internal & external photographs
Label sample
Schematic diagrams
User manual

Quality System documentation
ISO 9001 Certificate for manufacturer

Technical characteristics

Type of modulation:	FSK
Emission designator:	F1D
Operating frequency range:	928.35 MHz
Rated transmitter output power:	1 mW
Maximum antenna gain:	2.15 dBi

Other information
The device is certified for operation with the following antenna(s):
ANT 300, helical antenna, 2.15 dBi gain
Whip antenna, 64mm, -3.89 dBi gain
USB 400J, top loaded PCB spiral antenna, 1.14 dBi gain

EMCCert DR. RAŠEK GmbH • Stoernhofer Berg 15, 91364 Unterleinleiter, Germany
Tel.: +49-9194-72279-01 • Fax: +49-9194-72279-06 • E-mail: emc.cert@emcc.de • Web: www.emcc.de